

L Number	Hits	Search Text	DB	Time stamp
-	459	atomic adj layer adj deposit\$3	USPAT; US-PGPUB	2003/01/16 15:18
-	52911	tantalum adj nitride or TaN	USPAT; US-PGPUB	2003/01/16 17:18
-	34	(atomic adj layer adj deposit\$3) same (tantalum adj nitride or TaN)	USPAT; US-PGPUB	2003/01/16 15:19
-	52911	tantalum adj nitride or TaN	USPAT; US-PGPUB	2003/01/16 17:18
-	9910	diffusion near3 barrier	USPAT; US-PGPUB	2003/01/16 17:18
-	225723	capacitor	USPAT; US-PGPUB	2003/01/16 17:19
-	194	capacitor and ((tantalum adj nitride or TaN) same (diffusion near3 barrier))	USPAT; US-PGPUB	2003/01/16 18:35
-	158	(438/399).CCLS.	USPAT; US-PGPUB	2003/01/16 18:46
-	169800	barrier	USPAT; US-PGPUB	2003/01/16 18:46
-	2517	(tantalum adj nitride or TaN) same barrier	USPAT; US-PGPUB	2003/01/16 18:47
-	719	capacitor and ((tantalum adj nitride or TaN) same barrier)	USPAT; US-PGPUB	2003/01/16 18:50
-	1126616	opening	USPAT; US-PGPUB	2003/01/16 18:50
-	1095007	via	USPAT; US-PGPUB	2003/01/16 18:50
-	747368	hole	USPAT; US-PGPUB	2003/01/16 18:51
-	7642	diffusion adj barrier	USPAT; US-PGPUB	2003/01/16 18:52
-	284	(tantalum adj nitride or TaN) same (diffusion adj barrier) same (opening via hole)	USPAT; US-PGPUB	2003/01/16 18:53

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